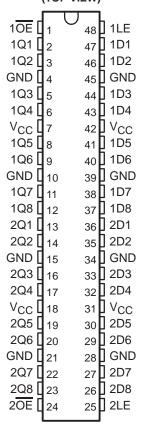
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- State-of-the-Art Advanced BiCMOS Technology (ABT) Widebus™ Design for 2.5-V and 3.3-V Operation and Low Static **Power Dissipation**
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 2.3-V to 3.6-V V_{CC})
- **Typical V_{OLP} (Output Ground Bounce)** $< 0.8 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- High Drive (-24/24 mA at 2.5-V and -32/64 mA at 3.3-V V_{CC})
- **Power Off Disables Outputs, Permitting Live Insertion**
- **High-Impedance State During Power Up** and Power Down Prevents Driver Conflict
- Uses Bus Hold on Data Inputs in Place of External Pullup/Pulldown Resistors to Prevent the Bus From Floating
- **Auto3-State Eliminates Bus Current** Loading When Output Exceeds V_{CC} + 0.5 V
- Latch-Up Performance Exceeds 250 mA Per **JESD 17**
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model; and Exceeds 1000 V **Using Charged-Device Model, Robotic** Method
- Flow-Through Architecture Facilitates **Printed Circuit Board Layout**
- Distributed V_{CC} and GND Pin Configuration **Minimizes High-Speed Switching Noise**
- **Package Options Include Plastic Shrink** Small-Outline (DL), Thin Shrink Small-Outline (DGG), Thin Very Small-Outline (DGV) Packages, and 380-mil Fine-Pitch Ceramic Flat (WD) Package

SN54ALVTH16373 . . . WD PACKAGE SN74ALVTH16373... DGG, DGV, OR DL PACKAGE (TOP VIEW)



description

The 'ALVTH16373 devices are 16-bit transparent D-type latches with 3-state outputs designed for 2.5-V or 3.3-V $V_{
m CC}$ operation, but with the capability to provide a TTL interface to a 5-V system environment. These devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

These devices can be used as two 8-bit latches or one 16-bit latch. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the levels set up at the D inputs.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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description (continued)

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

When V_{CC} is between 0 and 1.2 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.2 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

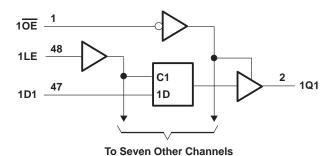
The SN54ALVTH16373 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ALVTH16373 is characterized for operation from –40°C to 85°C.

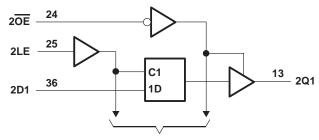
FUNCTION TABLE (each 8-bit section)

	INPUTS		OUTPUT
OE	LE	D	Q
L	Н	Н	Н
L	Н	L	L
L	L	Χ	Q ₀
Н	X	Χ	Z



logic diagram (positive logic)





To Seven Other Channels

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high-impedance	
or power-off state, V _O (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state, V _O (see Note 1)	–0.5 V to 7 V
Output current in the low state, IO: SN54ALVTH16373	96 mA
SN74ALVTH16373	
Output current in the high state, I _O : SN54ALVTH16373	–48 mA
SN74ALVTH16373	
Input clamp current, I _{IK} (V _I < 0)	–50 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Package thermal impedance, θ _{JA} (see Note 2): DGG package	89°C/W
DGV package	93°C/W
DL package	94°C/W
Storage temperature range, T _{sta} –	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

recommended operating conditions, V_{CC} = 2.5 V \pm 0.2 V (see Note 3)

			SN54	ALVTH1	6373	SN74	ALVTH1	6373	UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Vcc	CC Supply voltage				2.7	2.3		2.7	V
VIH	High-level input voltage					1.7			V
V _{IL}	Low-level input voltage			4	0.7			0.7	V
VI	Input voltage			VCC	5.5	0	VCC	5.5	V
ЮН	High-level output current			,0	-6			-8	mA
la	Low-level output current			Ç	6			8	mΑ
IOL	loL Low-level output current; current duty cycle ≤ 50%; f ≥ 1 kHz		5	5	18			24	IIIA
Δt/Δν	Input transition rise or fall rate Outputs enabled		St.		10			10	ns/V
Δt/ΔV _{CC}	C Power-up ramp rate		200			200			μs/V
TA	Operating free-air temperature				125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



^{2.} The package thermal impedance is calculated in accordance with JESD 51.

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recommended operating conditions, $V_{\mbox{\footnotesize{CC}}}$ = 3.3 V \pm 0.3 V (see Note 3)

			SN54	ALVTH1	6373	SN74	ALVTH1	6373	UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
VCC	Supply voltage				3.6	3		3.6	V
VIH	High-level input voltage		2			2			V
V _{IL}	Low-level input voltage			4	0.8			0.8	V
VI	Input voltage			VCC	5.5	0	VCC	5.5	V
IOH	High-level output current			Q	-24			-32	mA
la	Low-level output current			(0)	24			32	mA
IOL	Low-level output current; current duty cycle ≤ 50%; f ≥ 1 kHz		4	\tilde{Q}	48			64	IIIA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	8		10			10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate				·	200			μs/V
T _A	Operating free-air temperature				125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted)

	ND AMETED	TEST O	ONDITIONS	SN54	ALVTH1	6373	SN74	ALVTH1	6373	LINUT	
PA	ARAMETER	TEST	ONDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT	
VIK		$V_{CC} = 2.3 \text{ V},$	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	$I_{OH} = -100 \mu A$	V _{CC} -0.	2		V _{CC} -0	.2			
VOH		V _{CC} = 2.3 V	I _{OH} = -6 mA	1.8						V	
		vCC = 2.3 v	I _{OH} = -8 mA				1.8				
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	I _{OL} = 100 μA			0.2			0.2		
			I _{OL} = 6 mA			0.4					
VOL		V _{CC} = 2.3 V	$I_{OL} = 8 \text{ mA}$						0.4	V	
		V(C) = 2.5 V	I _{OL} = 18 mA			0.5					
			I _{OL} = 24 mA						0.5		
	Control inputs	$V_{CC} = 2.7 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1		
	Control inputs	$V_{CC} = 0 \text{ or } 2.7 \text{ V},$	V _I = 5.5 V			<u>\$</u> 10			10		
II			V _I = 5.5 V		, i	10			10	μΑ	
	Data inputs	V _{CC} = 2.7 V	VI = VCC		27	1			1		
			V _I = 0		1	- 5			– 5		
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V		25				±100	μΑ	
I _{BHL} ‡		$V_{CC} = 2.3 \text{ V},$	V _I = 0.7 V		115			115		μΑ	
IBHH§		$V_{CC} = 2.3 \text{ V},$	V _I = 1.7 V	Q	-10			-10		μΑ	
I _{BHLO}	,¶	$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	300			300			μΑ	
Івннс) [#]	$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	-300			-300			μΑ	
{IEX}		$V{CC} = 2.3 \text{ V},$	$V_0 = 5.5 \text{ V}$			125			125	μΑ	
IOZ(Pl	J/PD) [☆]	$V_{CC} \le 1.2 \text{ V}, V_{O} = 0.5 \text{ V}$ $V_{I} = \text{GND or } V_{CC}, \overline{\text{OE}} = 0.5 \text{ V}$	√ to V _{CC} , = don't care			±100			±100	μΑ	
lozh		V _{CC} = 2.7 V	$V_O = 2.3 \text{ V},$ $V_I = 0.7 \text{ V or } 1.7 \text{ V}$			5			5	μΑ	
lozL		V _{CC} = 2.7 V	$V_O = 0.5 \text{ V},$ $V_I = 0.7 \text{ V or } 1.7 \text{ V}$			-5			-5	μΑ	
		V00 = 2 7 V	Outputs high		0.04	0.1		0.04	0.1		
Icc		$V_{CC} = 2.7 \text{ V},$ $I_O = 0,$ $V_I = V_{CC} \text{ or GND}$	Outputs low	1	2.3	4.5		2.3	4.5	mA	
			Outputs disabled		0.04	0.1		0.04	0.1		
Ci		V _{CC} = 2.5 V,	V _I = 2.5 V or 0	1	3.5			3.5		pF	
Co		V _{CC} = 2.5 V,	V _O = 2.5 V or 0	1	6			6		pF	

[†] All typical values are at $V_{CC} = 2.5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.

[¶] An external driver must source at least IBHLO to switch this node from low to high.

[#]An external driver must sink at least IBHHO to switch this node from high to low.

Current into an output in the high state when VO > VCC

^{*}High-impedance state during power up or power down

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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted)

DA	DAMETER	TEST O	ONDITIONS	SN54	ALVTH1	6373	SN74	ALVTH1	6373	UNIT
PA	RAMETER	1531 C	ONDITIONS	MIN	TYP [†]	MAX	MIN	TYP†	MAX	UNII
VIK		V _{CC} = 3 V,	I _I = -18 mA			-1.2			-1.2	V
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OH} = -100 μA	V _{CC} -0.	2		V _{CC} -0	.2		
Vон		V 2.V	I _{OH} = -24 mA	2						V
		VCC = 3 V	I _{OH} = -32 mA				2			
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OL} = 100 μA			0.2			0.2	
			I _{OL} = 16 mA						0.4	V
\/0:			I _{OL} = 24 mA			0.5				
VOL		VCC = 3 V	$I_{OL} = 32 \text{ mA}$						0.5	V
			$I_{OL} = 48 \text{ mA}$			0.55				
	_		$I_{OL} = 64 \text{ mA}$				0.55			
	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1	
	Control inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V _I = 5.5 V		Á	10			10	
l _l			V _I = 5.5 V		72/2	10			10	μΑ
	Data inputs	V _{CC} = 3.6 V	VI = VCC		1	1			1	
			V _I = 0		2	- 5			– 5	
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V	0	2				±100	μΑ
I _{BHL} ‡		$V_{CC} = 3 V$,	V _I = 0.8 V	75			75			μΑ
I _{BHH} §		V _{CC} = 3 V,	V _I = 2 V	-75			-75			μΑ
^I BHLO	1	$V_{CC} = 3.6 \text{ V},$	$V_I = 0$ to V_{CC}	500			500			μΑ
Івнно	, #	$V_{CC} = 3.6 \text{ V},$	$V_I = 0$ to V_{CC}	-500			-500			μΑ
I _{EX}		$V_{CC} = 3 V$,	V _O = 5.5 V			125			125	μΑ
IOZ(PL	J/PD)☆	$V_{CC} \le 1.2 \text{ V}, V_{O} = \underline{0.5} \text{ V}$ $V_{I} = \text{GND or } V_{CC}, \overline{\text{OE}} = \underline{0.5} \text{ V}$	V to V _{CC} , = don't care			±100			±100	μΑ
lozh		V _{CC} = 3.6 V	V _O = 3 V,			5			5	μΑ
			V _I = 0.8 V or 2 V							
lozL		V _{CC} = 3.6 V	$V_0 = 0.5 \text{ V},$			-5			-5	μΑ
			V _I = 0.8 V or 2 V		0.07		<u> </u>		0.4	
		$V_{CC} = 3.6 \text{ V},$	Outputs high		0.07	0.1		0.07	0.1	
ICC		$I_O = 0$, $V_I = V_{CC}$ or GND	Outputs low	-	3.2	5.5		3.2	5	mA
			Outputs disabled	₩	0.07	0.1		0.07	0.1	
∆lCC□		V _{CC} = 3 V to 3.6 V, One Other inputs at V _{CC} or	e input at V _{CC} – 0.6 V, GND			0.4			0.4	mA
C _i		$V_{CC} = 3.3 \text{ V},$	$V_{I} = 3.3 \text{ V or } 0$		3.5			3.5		pF
Co		V _{CC} = 3.3 V,	V _O = 3.3 V or 0		6			6		pF

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{II} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at VIH min. IBHH should be measured after raising VIN to VCC and then lowering it to VIH min.

 $[\]P$ An external driver must source at least $I_{\mbox{\footnotesize{BHLO}}}$ to switch this node from low to high.

[#] An external driver must sink at least IBHHO to switch this node from high to low.

Current into an output in the high state when VO > VCC

[★]High-impedance state during power up or power down

[□]This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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timing requirements over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

			SN54ALVTH16373	SN74ALVTH	116373	UNIT
		MIN MAX	MIN	MAX	UNIT	
t _W	Pulse duration, LE high		1.5	1.5		ns
	t _{Su} Setup time, data before LE↓	Data high	1.1,0	1		ns
^l su		Data low	1.6	1.5	1.5	
+.	t _h Hold time, data after LE↓	Data high	\$1	0.9		ns
יח		Data low	1.6	1.5		115

timing requirements over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 2)

			SN54ALVTI	H16373	SN74ALVT	H16373	UNIT	
			MIN	MAX	MIN	MAX	UNIT	
t _W	Pulse duration, LE high		1.5	\\\ \(\) \(\) \(\)	1.5		ns	
	Cotum time data before LE	Data high	1.5		1.4		20	
t _{su}	Setup time, data before LE↓	Data low	0		0.9		ns	
tı.	Hold time, data after LE↓	Data high	Q1		0.9	·	ns	
th	noid time, data arter LE↓	Data low	1.5		1.4		1115	

switching characteristics over recommended operating free-air temperature range, C_L = 30 pF, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

00		, ,					
PARAMETER	FROM	то	SN54ALVTH16373	SN74ALVT	SN74ALVTH16373		
PARAMETER	(INPUT)	(OUTPUT)	MIN MAX	MIN	MAX	UNIT	
^t PLH	D	Q	1 3.4	1	3.3	ns	
t _{PHL}		ď	1 4.3	1	4.2	115	
t _{PLH}	LE	Q	1.4 3.9	1.5	3.8	ns	
t _{PHL}	LE	ď	1.4 4.6	1.5	4.5	115	
^t PZH	OE	Q	1.7 4.4	1.8	4.3		
t _{PZL}	OE .	ď	1,4 4.1	1.5	4	ns	
^t PHZ	OE	Q	1.4 4.7	1.5	4.6	ns	
t _{PLZ}			1 3.7	1	3.6	115	

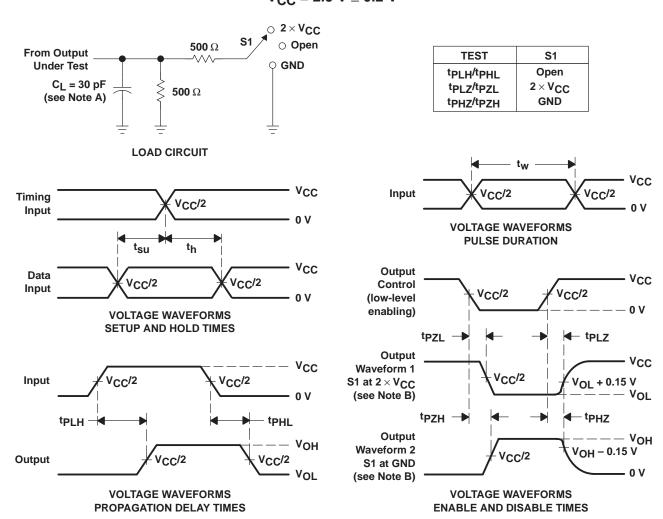
switching characteristics over recommended operating free-air temperature range, C_L = 50 pF, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	то	SN54ALVTH16373	SN74ALVTH16373	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN MAX	XAM MIM MAX	
tPLH	D	Q	1 3.2	2 1 3.1]
^t PHL	D	<u> </u>	1 3.4	1 3.3	ns
^t PLH	LE	Q	1 3.4	1 3.3	ns
^t PHL	LL	ď	1 2 3.6	1 3.5	115
^t PZH	ŌĒ	Q	1.3 4.1	1.4	ns
^t PZL	OE	3	3.5	5 1 3.4	. 115
^t PHZ	ŌĒ	Q	1.4 5	1.5 4.9	ns
t _{PLZ}	OE	3	1.4 4.6	1.5 4.5	



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PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



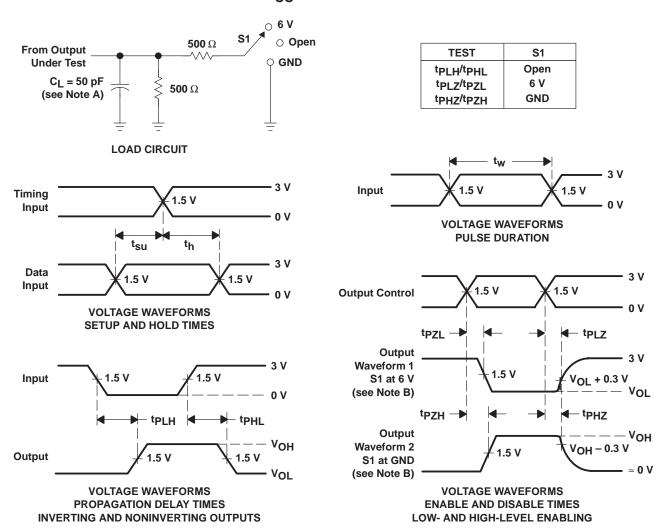
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \Omega$, $t_f \leq 2$ ns, $t_f \leq 2$ ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform22 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50~\Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms

PACKAGE OPTION ADDENDUM





PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74ALVTH16373DLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16373DLRG4	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16373GRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16373GRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16373VRE4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16373VRG4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16373ZQLR	ACTIVE	BGA MI CROSTA R JUNI OR	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
SN74ALVTH16373DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16373DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16373GR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16373KR	NRND	BGA MI CROSTA R JUNI OR	GQL	56	1000	TBD	SNPB	Level-1-240C-UNLIM
SN74ALVTH16373VR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the



PACKAGE OPTION ADDENDUM

27-Sep-2007

accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

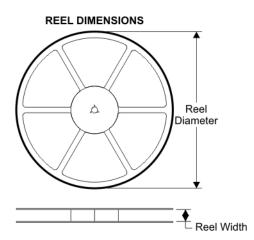
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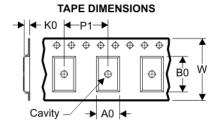




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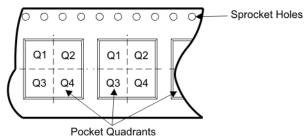
TAPE AND REEL BOX INFORMATION





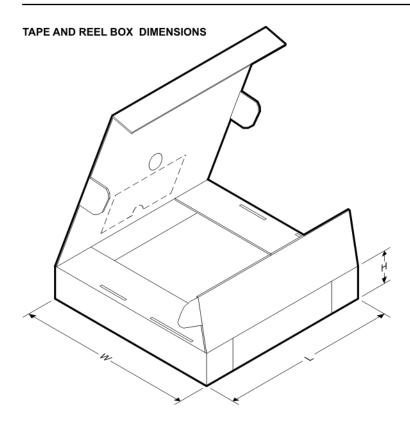
	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74ALVTH16373ZQLR	ZQL	56	SITE 32	330	16	4.8	7.3	1.45	8	16	Q1
SN74ALVTH16373DLR	DL	48	SITE 41	330	32	11.35	16.2	3.1	16	32	Q1
SN74ALVTH16373GR	DGG	48	SITE 41	330	24	8.6	15.8	1.8	12	24	Q1
SN74ALVTH16373KR	GQL	56	SITE 32	330	16	4.8	7.3	1.45	8	16	Q1
SN74ALVTH16373VR	DGV	48	SITE 41	330	24	6.8	10.1	1.6	12	24	Q1

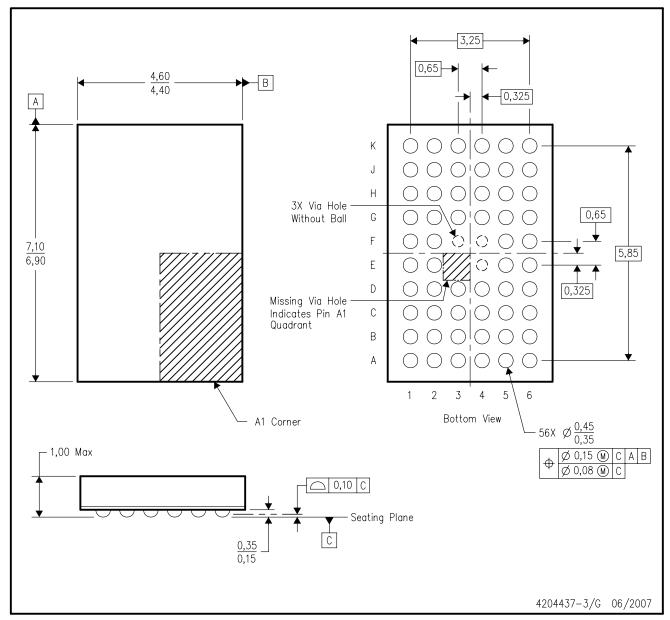




Device	Package	Pins Site		Length (mm)	Width (mm)	Height (mm)	
74ALVTH16373ZQLR	ZQL	56	SITE 32	346.0	346.0	0.0	
SN74ALVTH16373DLR	DL	48	SITE 41	346.0	346.0	0.0	
SN74ALVTH16373GR	DGG	48	SITE 41	346.0	346.0	0.0	
SN74ALVTH16373KR	GQL	56	SITE 32	346.0	346.0	0.0	
SN74ALVTH16373VR	DGV	48	SITE 41	346.0	346.0	0.0	

ZQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is lead-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

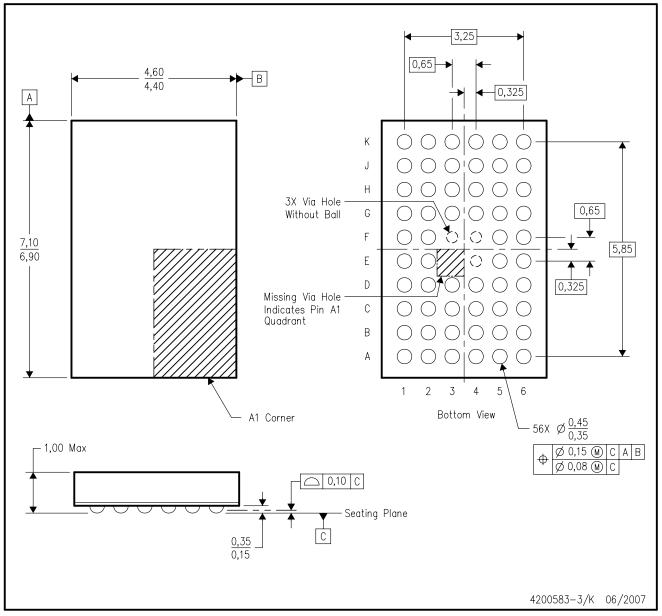
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



DL (R-PDSO-G**)

48 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MO-118

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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